

GenX3™ 300V IGBTs

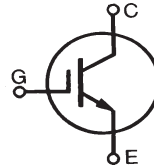
IXGK400N30A3 IXGX400N30A3

$$V_{CES} = 300V$$

$$I_{C25} = 400A$$

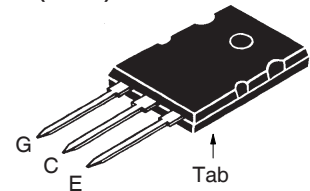
$$V_{CE(sat)} \leq 1.15V$$

Ultra-Low V_{sat} PT IGBTs for
up to 10kHz Switching

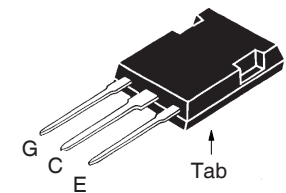


| Symbol | Test Conditions | Maximum Ratings | |
|-------------------------------|---|---|------------|
| V_{CES} | $T_J = 25^\circ C$ to $150^\circ C$ | 300 | V |
| V_{CGR} | $T_J = 25^\circ C$ to $150^\circ C$, $R_{GE} = 1M\Omega$ | 300 | V |
| V_{GES} | Continuous | ± 20 | V |
| V_{GEM} | Transient | ± 30 | V |
| I_{C25} | $T_C = 25^\circ C$ (Chip Capability) | 400 | A |
| I_{C110} | $T_C = 110^\circ C$ | 200 | A |
| I_{LRMS} | Terminal Current Limit | 160 | A |
| I_{CM} | $T_C = 25^\circ C$, 1ms | 1200 | A |
| SSOA (RBSOA) | $V_{GE} = 15V$, $T_{VJ} = 125^\circ C$, $R_G = 1\Omega$ Clamped Inductive Load | $I_{CM} = 400$ @ $0.8 \cdot V_{CES}$ | A |
| P_C | $T_C = 25^\circ C$ | 1000 | W |
| T_J | | -55 ... +150 | $^\circ C$ |
| T_{JM} | | 150 | $^\circ C$ |
| T_{stg} | | -55 ... +150 | $^\circ C$ |
| T_L | Maximum Lead Temperature for Soldering | 300 | $^\circ C$ |
| T_{SOLD} | 1.6 mm (0.062 in.) from Case for 10 | 260 | $^\circ C$ |
| M_d | Mounting Torque (IXGK) | 1.13/10 | Nm/lb.in. |
| F_c | Mounting Force (IXGX) | 20..120/4.5..27 | N/lb. |
| Weight | TO-264 | 10 | g |
| | PLUS247 | 6 | g |

TO-264 (IXGK)



PLUS247™ (IXGX)



G = Gate E = Emitter
C = Collector Tab = Collector

Features

- Optimized for Low Conduction Losses
- High Avalanche Capability
- International Standard Packages

Advantages

- High Power Density
- Low Gate Drive Requirement

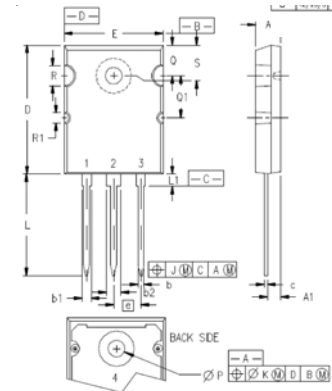
Applications

- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts
- Inrush Current Protection Circuits

| Symbol | Test Conditions ($T_J = 25^\circ C$, Unless Otherwise Specified) | Characteristic Values | | |
|---------------|---|-----------------------|------|--------------------|
| | | Min. | Typ. | Max. |
| BV_{CES} | $I_C = 1mA$, $V_{GE} = 0V$ | 300 | | V |
| $V_{GE(th)}$ | $I_C = 4mA$, $V_{CE} = V_{GE}$ | 3.0 | | 5.0 V |
| I_{CES} | $V_{CE} = V_{CES}$, $V_{GE} = 0V$ $T_J = 125^\circ C$ | | | 50 μA 2 mA |
| I_{GES} | $V_{CE} = 0V$, $V_{GE} = \pm 20V$ | | | ± 400 nA |
| $V_{CE(sat)}$ | $I_C = 100A$, $V_{GE} = 15V$, Note 1 $I_C = 400A$ | 1.70 | 1.15 | V V |

| Symbol | Test Conditions ($T_J = 25^\circ\text{C}$, Unless Otherwise Specified) | Characteristic Values | | |
|--------------|---|--|-------|--------------------|
| | | Min. | Typ. | Max. |
| g_{fs} | $I_C = 60\text{A}$, $V_{CE} = 10\text{V}$, Note 1 | 100 | 170 | S |
| C_{ies} | $V_{CE} = 25\text{V}$, $V_{GE} = 0\text{V}$, $f = 1\text{MHz}$ | | 19 | nF |
| C_{oes} | | | 1350 | pF |
| C_{res} | | | 190 | pF |
| $Q_{g(on)}$ | $I_C = 100\text{A}$, $V_{GE} = 15\text{V}$, $V_{CE} = 0.5 \cdot V_{CES}$ | | 560 | nC |
| Q_{ge} | | | 83 | nC |
| Q_{gc} | | | 185 | nC |
| $t_{d(on)}$ | Resistive load, $T_J = 25^\circ\text{C}$ | | 45 | ns |
| t_r | | | 45 | ns |
| $t_{d(off)}$ | $I_C = 100\text{A}$, $V_{GE} = 15\text{V}$ | | 210 | ns |
| t_f | | $V_{CE} = 240\text{V}$, $R_G = 1\Omega$ | | 107 |
| $t_{d(on)}$ | Resistive load, $T_J = 125^\circ\text{C}$ | | 47 | ns |
| t_r | | | 53 | ns |
| $t_{d(off)}$ | $I_C = 100\text{A}$, $V_{GE} = 15\text{V}$ | | 240 | ns |
| t_f | | $V_{CE} = 240\text{V}$, $R_G = 1\Omega$ | | 315 |
| R_{thJC} | | | 0.125 | $^\circ\text{C/W}$ |
| R_{thCK} | | 0.15 | | $^\circ\text{C/W}$ |

TO-264 (IXGK) Outline

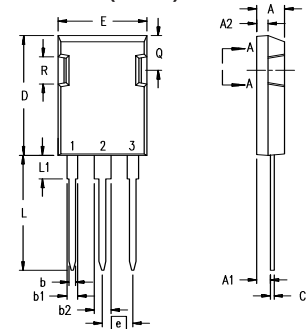


1 - GATE
2, 4 - DRAIN (COLLECTOR)
3 - SOURCE (EMITTER)

| SYM | INCHES | | MILLIMETERS | |
|-----|----------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .185 | .209 | 4.70 | 5.31 |
| A1 | .102 | .118 | 2.59 | 3.00 |
| b | .037 | .055 | 0.94 | 1.40 |
| b1 | .087 | .102 | 2.21 | 2.59 |
| b2 | .110 | .126 | 2.79 | 3.20 |
| c | .017 | .029 | 0.43 | 0.74 |
| D | 1.007 | 1.047 | 25.58 | 26.59 |
| E | .760 | .789 | 19.30 | 20.29 |
| e | .215 BSC | | 5.46 BSC | |
| J | .000 | .010 | 0.00 | 0.25 |
| K | .000 | .010 | 0.00 | 0.25 |
| L | .779 | .842 | 19.79 | 21.39 |
| L1 | .087 | .102 | 2.21 | 2.59 |
| Q | .240 | .256 | 6.10 | 6.50 |
| Q1 | .330 | .346 | 8.38 | 8.79 |
| Q | .240 | .256 | 6.10 | 6.50 |
| Q1 | .330 | .346 | 8.38 | 8.79 |
| ØR | .155 | .187 | 3.94 | 4.75 |
| ØR1 | .085 | .093 | 2.16 | 2.36 |
| S | .243 | .253 | 6.17 | 6.43 |

Note 1. Pulse test, $t \leq 300\mu\text{s}$, duty cycle, $d \leq 2\%$.

PLUS247™ (IXGX) Outline



Terminals: 1 - Gate
2 - Drain (Collector)
3 - Source (Emitter)

| Dim. | Millimeter | | Inches | |
|----------------|------------|-------|----------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.83 | 5.21 | .190 | .205 |
| A ₁ | 2.29 | 2.54 | .090 | .100 |
| A ₂ | 1.91 | 2.16 | .075 | .085 |
| b | 1.14 | 1.40 | .045 | .055 |
| b ₁ | 1.91 | 2.13 | .075 | .084 |
| b ₂ | 2.92 | 3.12 | .115 | .123 |
| C | 0.61 | 0.80 | .024 | .031 |
| D | 20.80 | 21.34 | .819 | .840 |
| E | 15.75 | 16.13 | .620 | .635 |
| e | 5.45 BSC | | .215 BSC | |
| L | 19.81 | 20.32 | .780 | .800 |
| L1 | 3.81 | 4.32 | .150 | .170 |
| Q | 5.59 | 6.20 | .220 | 0.244 |
| R | 4.32 | 4.83 | .170 | .190 |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

Fig. 1. Output Characteristics @ $T_J = 25^\circ\text{C}$

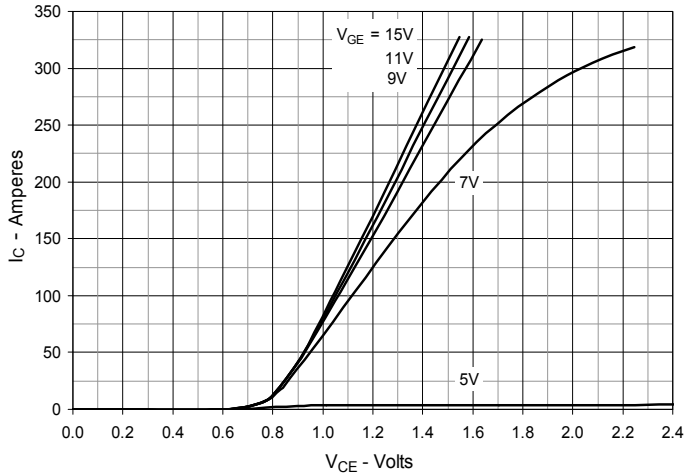


Fig. 2. Output Characteristics @ $T_J = 125^\circ\text{C}$

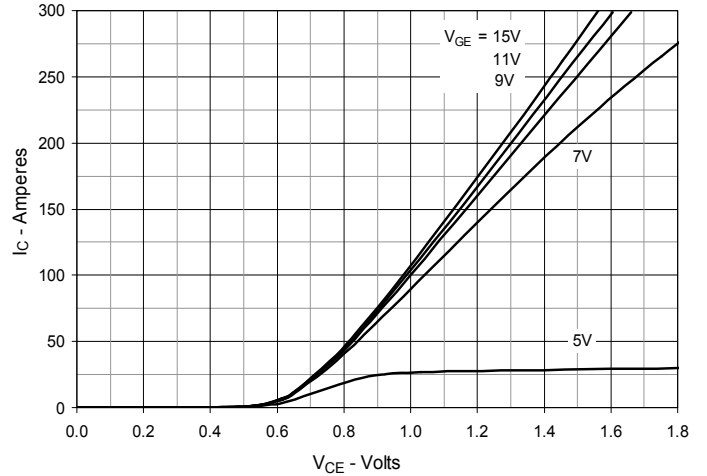


Fig. 3. Dependence of $V_{CE(sat)}$ on Junction Temperature

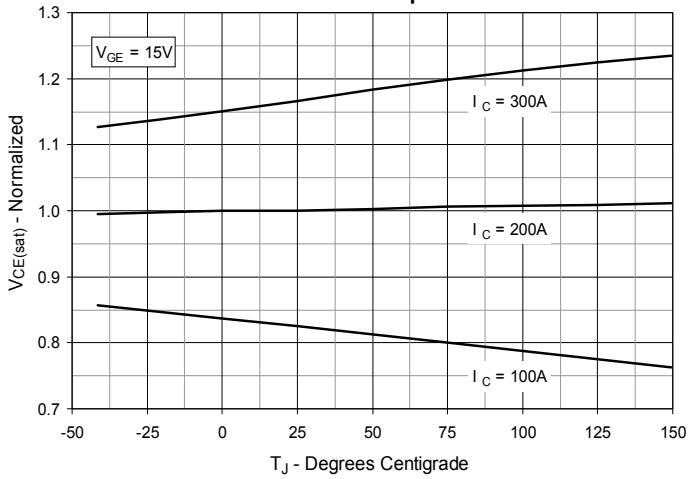


Fig. 4. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage

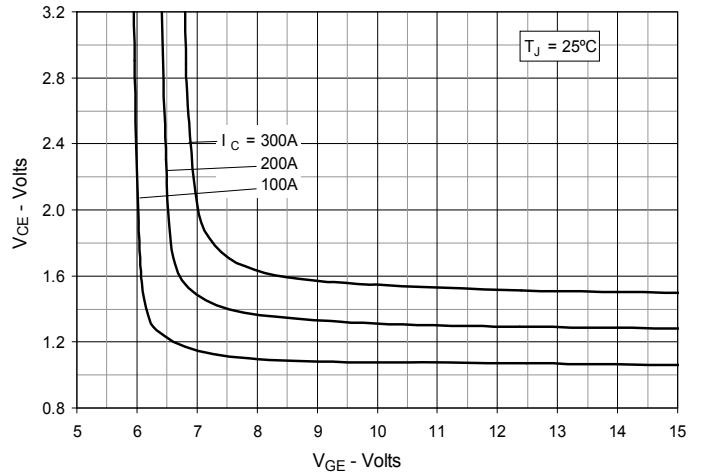


Fig. 5. Input Admittance

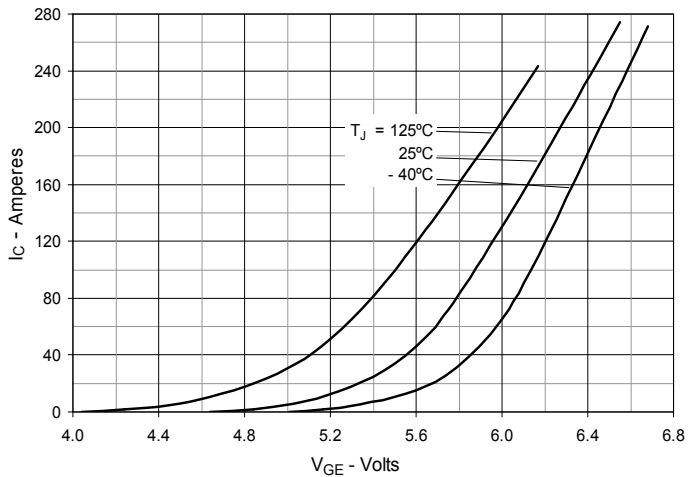


Fig. 6. Transconductance

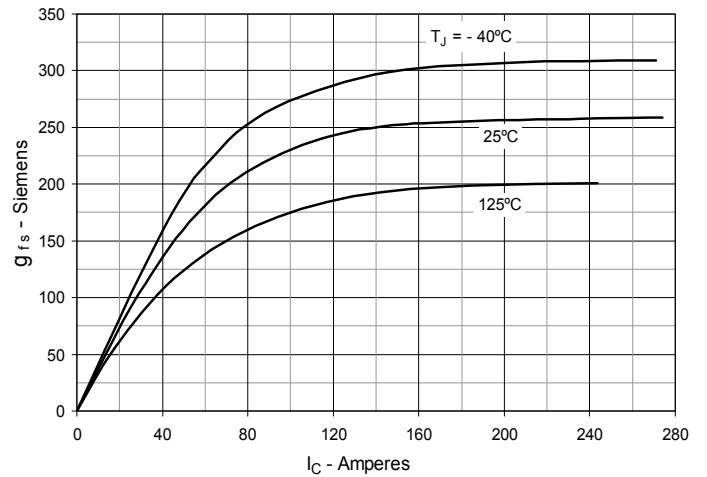


Fig. 7. Gate Charge

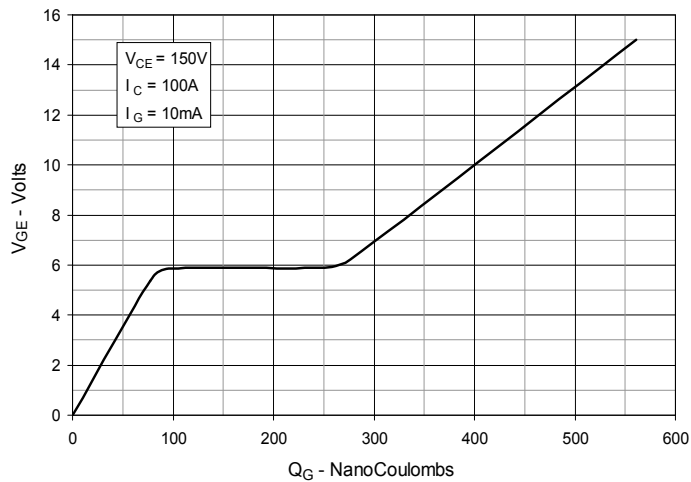


Fig. 8. Capacitance

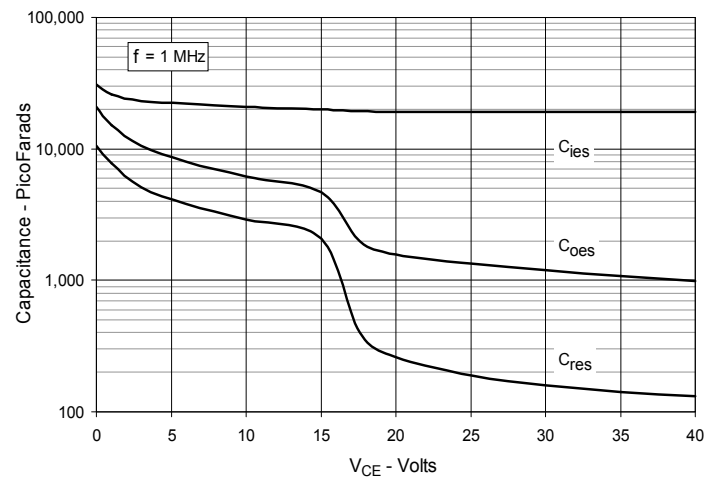


Fig. 9. Reverse-Bias Safe Operating Area

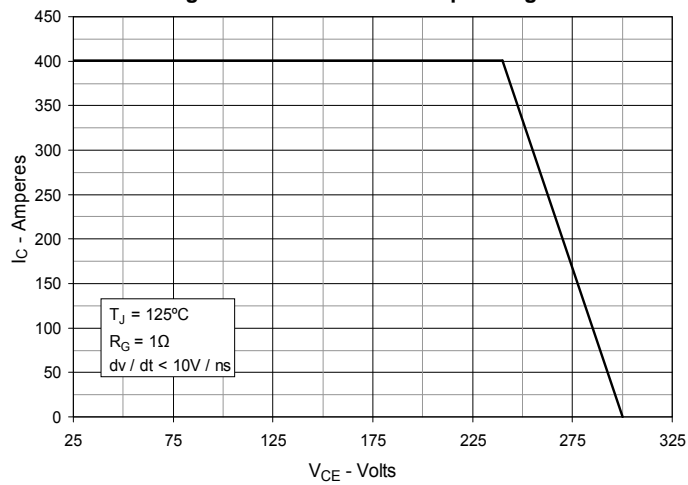


Fig. 10. Maximum Transient Thermal Impedance

